

**AMENDMENTS TO THE SPECIFICATION**

Kindly amend the title of the invention as follows:

~~A NITRIDE SEMICONDUCTOR ELEMENT WITH A SUPPORTING SUBSTRATE  
AND A METHOD FOR PRODUCING A NITRIDE SEMICONDUCTOR ELEMENT~~

Please insert the following paragraph beginning at page 1, before line 5:

This is a Divisional Application of U.S. Application No. 10/351,497, filed  
January 27, 2003.